# Panasonic

Zener Diode

### DZ2J390×0L Silicon epitaxial planar type

#### For constant voltage / For surge absorption circuit

- Features
- · Excellent rising characteristics of zener current Iz
- Low zener operating resistance Rz
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL:Level 1 compliant)
- Marking Symbol: LG or LR

#### Packaging

Embossed type (Thermo-compression sealing): 3 000 pcs / reel (standard)

■ Absolute Maximum Ratings Ta = 25 °C					
Parameter	Symbol	Rating	Unit		
Repetitive peak forward current	IFRM	200	mA		
Total power dissipation <sup>*1</sup>	PT	200	mW		
Electrostatic discharge *2	ESD	±8	kV		
Junction temperature	Tj	150	°C		
Operating ambient temperature	Topr	-40 to +85	°C		

 
 Storage temperature
 Tstg
 -55
 to
 +150
 °C

 Note)
 \*1
 Mounted on glass epoxy print board (45 mm × 45 mm × 1 mm) Solder in (Recommended land pattern)
 Solder in (Recommended land pattern)

\*2 Test method : IEC61000\_4\_2

(C = 150 pF, R = 330  $\Omega$ , Contact discharge : 10 times )

#### ■ Electrical Characteristics Ta = 25 °C ± 3 °C

\*3 Tj = 25 °C to 150 °C

Electrical Characteristics Ta - 25 C ± 5 C						
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Forward voltage	VF	IF = 10 mA			1.0	V
Zener voltage <sup>*1, *2</sup>	VZ	IZ = 2 mA	37.05		40.95	V
Zener operating resistance	RZ	IZ = 2 mA			300	Ω
Zener rise operating resistance	RZK	IZ = 0.5 mA			300	Ω
Reverse current	IR	VR = 30 V			0.05	μA
Temperature coefficient of zener voltage *3	SZ	IZ = 2 mA		37.2		mV/°C

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 Measuring methods for Diodes.

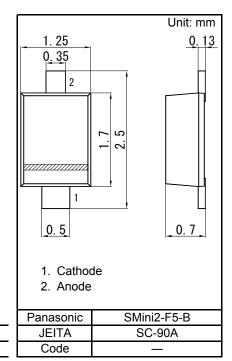
2. Absolute frequency of input and output is 5 MHz.

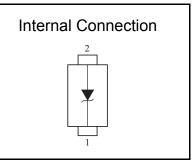
3. \*1 The temperature must be controlled 25 °C for VZ mesurement.

VZ value measured at other temperature must be adjusted to VZ (25 °C).

\*2 VZ guaranted 20 ms after current flow Rank classification

Code		Μ		0		
Rank		Μ		No-rank		nk
VZ	38.03	to	39.98	37.05	to	40.95
Marking symbol	LR		LG			

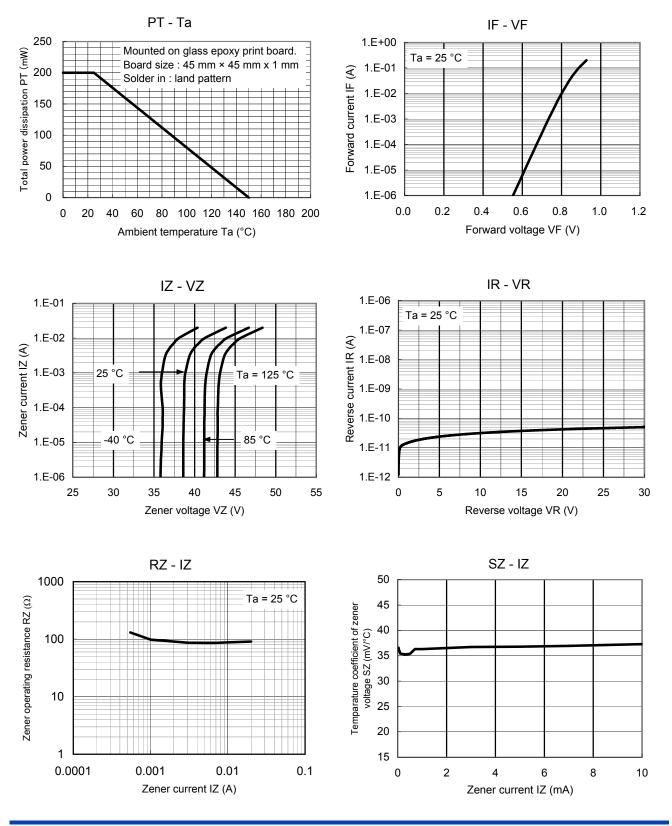






Zener Diode DZ2J390×0L

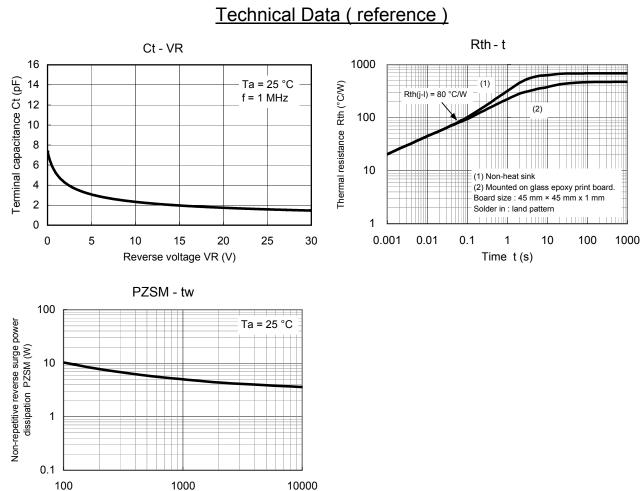
#### Technical Data (reference)



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Established : 2009-10-14 Revised : 2013-07-16 **Panasonic** 

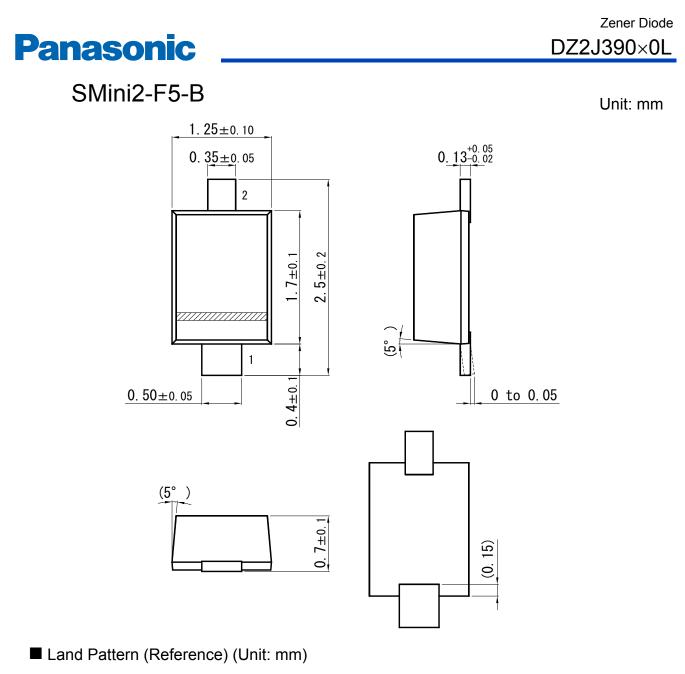
Zener Diode DZ2J390×0L

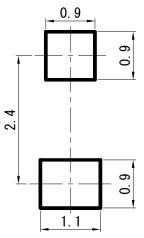


10000

Pulse width tw (µs)

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